Poster Presentation

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The electronic and magnetic properties of strained La0.85Zr0.15MnO3 films

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The electronic and magnetic properties of strained tetravalent-ion-doped La0.85Zr0.15MnO3 (LZMO) thin films that were epitaxially grown on SrTiO3 (STO) and MgO substrates were studied using temperature-dependent x-ray diffraction (XRD), x-ray absorption nearedge structure (XANES), x-ray linear dichroism (XLD) and x-ray magnetic circular dichroism (XMCD) at the Mn L3,2- and K-edge. XRD studies reveal that the LZMO thin films have compressive and tensile strains on the STO and MgO substrates, respectively. As temperature is reduced from room temperature to below magnetic transition temperature, the preferentially occupied Mn majority-spin eg orbital changes from the in-plane dx2-y2 to the out-of-plane d3z2-r2 orbital for LZMO/STO, and vice versa for LZMO/MgO. Experimental results suggest that the new hopping path that is mediated by the Mn2+ ions triggers a stronger d3z2-r2 orbital ordering of Mn3+ ions and enhances the ferromagnetic coupling between the Mn spin moments of t2g electrons in LZMO/STO, whereas the tensile strain stabilizes the dx2-y2 orbital by inducing lattice distortions of the MnO6 octahedra in LZMO/MgO.

Keywords: XANES, XLD, XMCD